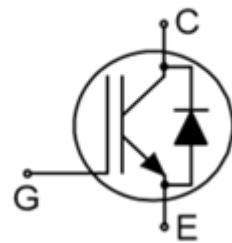


Trench Field-Stop Technology IGBT

Features

- 650V, 40A
- $V_{CE(\text{sat})(\text{typ.})} = 1.95\text{V}$ @ $V_{GE}=15\text{V}$, $I_C=40\text{A}$
- Low Gate charge
- Trench FS Technology
- RoHS product



Applications

- General purpose inverters
- UPS
- Motor control

| Order codes | V_{CE} | I_C | $V_{CE(\text{sat})}$, $T_{vj}=25^\circ\text{C}$ | $T_{vj\text{max}}$ | Marking | Package |
|--------------|----------|-------|--|--------------------|-----------|---------|
| XD040H065AY1 | 650V | 40A | 1.95V | 175°C | D40H65AY1 | TO247 |

Absolute Maximum Ratings

| Symbol | Parameter | Value | Unit |
|-----------|--|------------|------|
| V_{CES} | Collector-Emitter Voltage | 650 | V |
| V_{GES} | Gate-Emitter Voltage | ± 20 | V |
| I_C | Continuous Collector Current ($T_c=25^\circ\text{C}$) | 80 | A |
| | Continuous Collector Current ($T_c=100^\circ\text{C}$) | 40 | A |
| I_{CM} | Pulsed Collector Current (Note 1) | 160 | A |
| I_F | Diode Continuous Forward Current ($T_c=100^\circ\text{C}$) | 40 | A |
| I_{FM} | Diode Maximum Forward Current (Note 1) | 160 | A |
| t_{sc} | Short Circuit Withstand Time | 10 | us |
| P_D | Maximum Power Dissipation ($T_c=25^\circ\text{C}$) | 340 | W |
| | Maximum Power Dissipation ($T_c=100^\circ\text{C}$) | 170 | W |
| T_J | Operating Junction Temperature Range | -55 to 175 | °C |
| T_{STG} | Storage Temperature Range | -55 to 150 | °C |

Thermal Data

| Symbol | Parameter | Max. | Unit |
|-----------------|--|------|------|
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case for IGBT | 0.44 | °C/W |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case for Diode | 0.81 | °C/W |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient | 40 | °C/W |

Electrical Characteristics ($T_c=25^\circ\text{C}$ unless otherwise noted)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|---------------|--------------------------------------|--|------|------|------|---------|
| BV_{CES} | Collector-Emitter Breakdown Voltage | $V_{GE}=0V, I_c=250\mu A$ | 650 | --- | --- | V |
| I_{CES} | Collector-Emitter Leakage Current | $V_{CE}=650V, V_{GE}=0V$ | --- | --- | 40 | μA |
| I_{GES} | Gate Leakage Current, Forward | $V_{GE}=20V, V_{CE}=0V$ | --- | --- | 200 | nA |
| | Gate Leakage Current, Reverse | $V_{GE}=-20V, V_{CE}=0V$ | --- | --- | -200 | nA |
| $V_{GE(th)}$ | Gate Threshold Voltage | $V_{GE}=V_{CE}, I_c=250\mu A$ | 4.5 | --- | 6.5 | V |
| $V_{CE(sat)}$ | Collector-Emitter Saturation Voltage | $V_{GE}=15V, I_c=40A$ | --- | 1.95 | 2.4 | V |
| Q_G | Total Gate Charge | $V_{CC}=480V$ $V_{GE}=15V$ $I_c=40A$ | --- | 79.2 | --- | nC |
| Q_{GE} | Gate-Emitter Charge | | --- | 24.6 | --- | nC |
| Q_{GC} | Gate-Collector Charge | | --- | 34.1 | --- | nC |
| $t_{d(on)}$ | Turn-on Delay Time | $V_{CC}=400V$ $V_{GE}=15V$ $I_c=40A$ $R_G=10.5\Omega$ Inductive Load $T_C=25^\circ C$ | --- | 24 | --- | ns |
| t_r | Turn-on Rise Time | | --- | 84 | --- | ns |
| $t_{d(off)}$ | Turn-off Delay Time | | --- | 70 | --- | ns |
| t_f | Turn-off Fall Time | | --- | 78 | --- | ns |
| E_{on} | Turn-on Switching Loss | | --- | 1.11 | --- | mJ |
| E_{off} | Turn-off Switching Loss | | --- | 1.11 | --- | mJ |
| E_{ts} | Total Switching Loss | | --- | 2.22 | --- | mJ |
| C_{ies} | Input Capacitance | | --- | 2392 | --- | pF |
| C_{oes} | Output Capacitance | $V_{CE}=25V$ $V_{GE}=0V$ $f=1MHz$ | --- | 193 | --- | pF |
| C_{res} | Reverse Transfer Capacitance | | --- | 64.5 | --- | pF |

Diode Characteristics ($T_C=25^\circ C$ unless otherwise noted)

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|----------|-------------------------------------|--|------|------|------|---------|
| V_F | Diode Forward Voltage | $I_F=20A$ | --- | 1.5 | 2.5 | V |
| t_{rr} | Diode Reverse Recovery Time | $V_{CE}=400V$ $I_F=15A$ $dI_F/dt=1000A/us$ | --- | 36 | --- | ns |
| I_{rr} | Diode Peak Reverse Recovery Current | | --- | 10 | --- | A |
| Q_{rr} | Diode Reverse Recovery Charge | | --- | 0.3 | --- | μC |

Note 1: Repetitive Rating: Pulse width limited by maximum junction temperature

Typical Characteristics

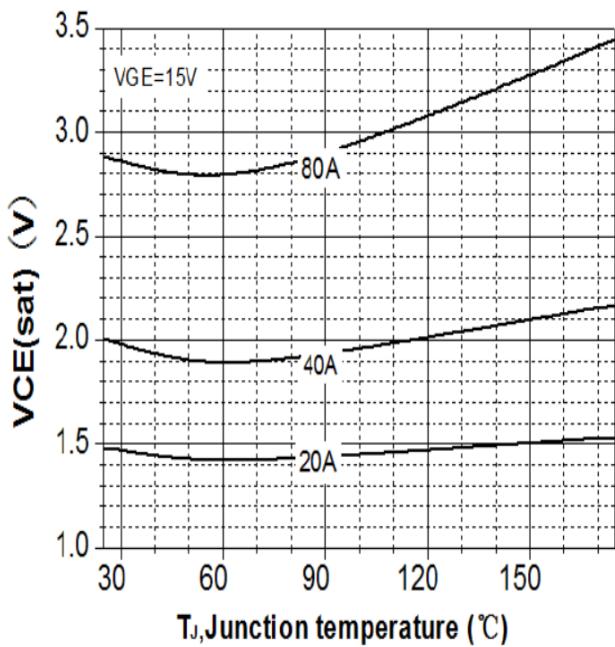


Fig. 1 Typical Collector-Emitter Saturation Voltage
vs. Junction Temperature ($V_{GE}=15V$)

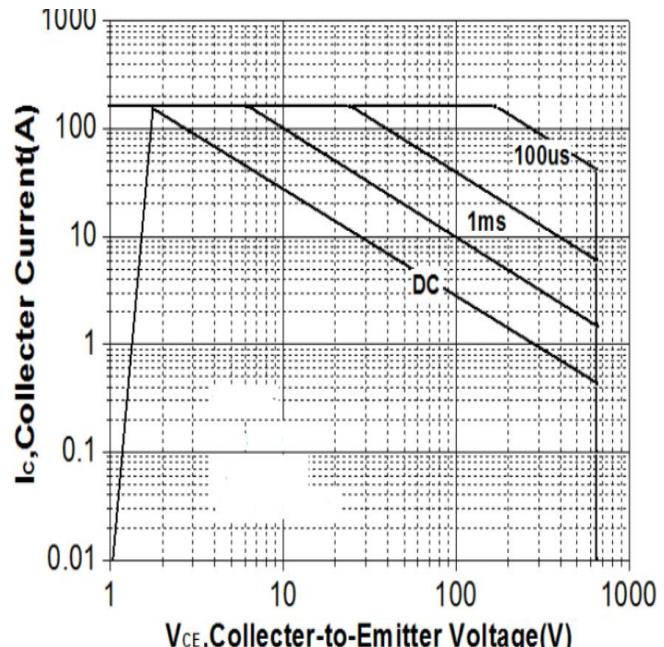


Fig. 2 Safe Operating Area at $T_c=25^\circ C$ and $T_j \leq 175^\circ C$

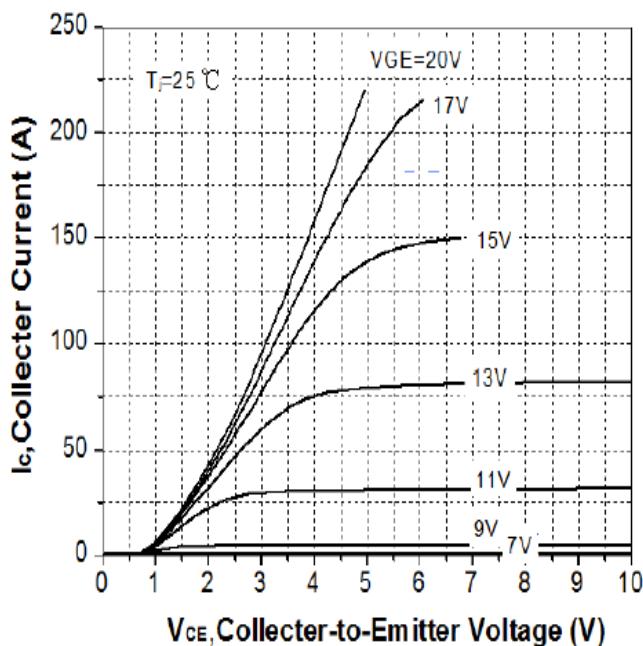


Fig. 3 Typical IGBT Output Characteristics at $T_j=25^\circ C$

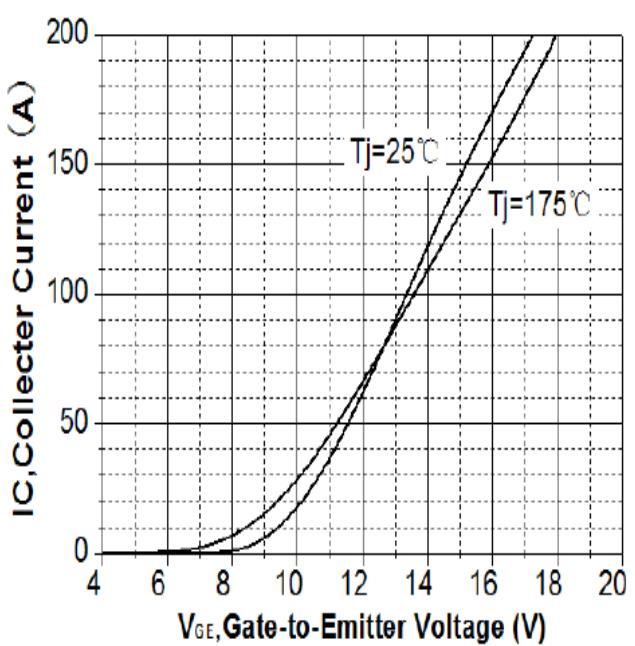


Fig. 4 Typical Transfer Characteristics at
 $V_{CE}=20V$

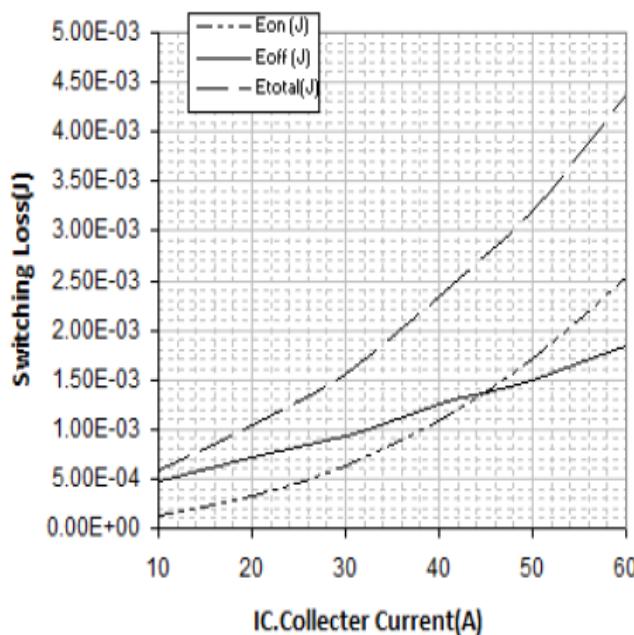


Fig. 5 Typical Energy Loss vs. I_c at $T_c=25^\circ\text{C}$,
 $V_{CE}=400\text{V}$, $V_{GE}=\pm 15\text{V}$ and $R_g=10.5\Omega$

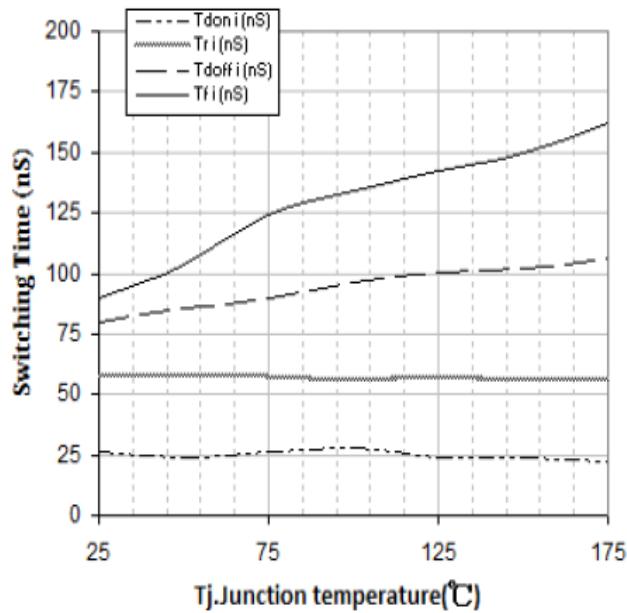


Fig. 6 Typical Switching Time vs. I_c at $T_c=25^\circ\text{C}$,
 $V_{CE}=400\text{V}$, $V_{GE}=\pm 15\text{V}$ and $R_g=10.5\Omega$

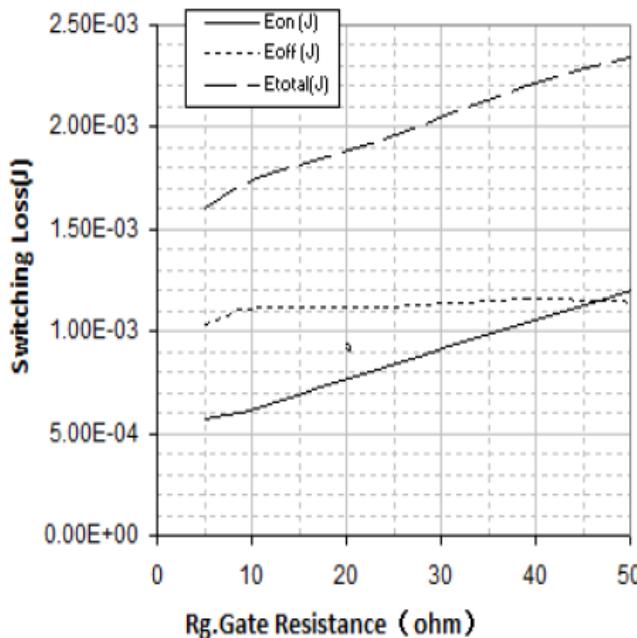


Fig. 7 Typical Energy Loss vs. R_g at $T_c=25^\circ\text{C}$,
 $V_{CE}=400\text{V}$, $V_{GE}=15\text{V}$, $I_c=15\text{A}$ and $R_g=10.5\Omega$

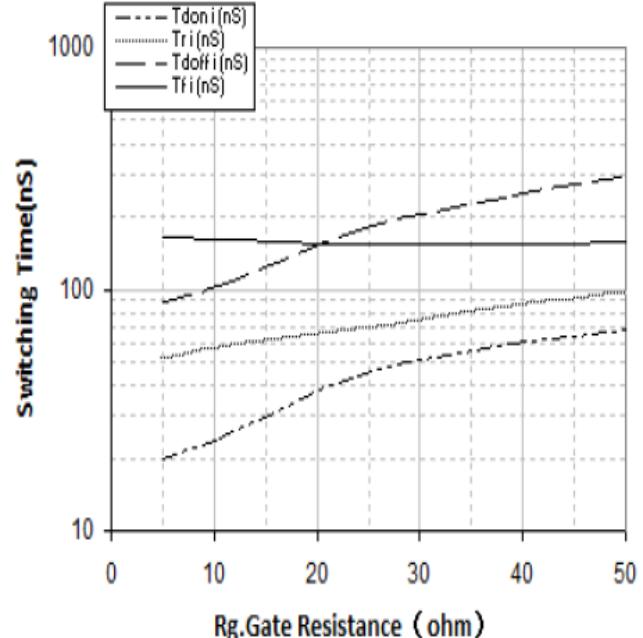
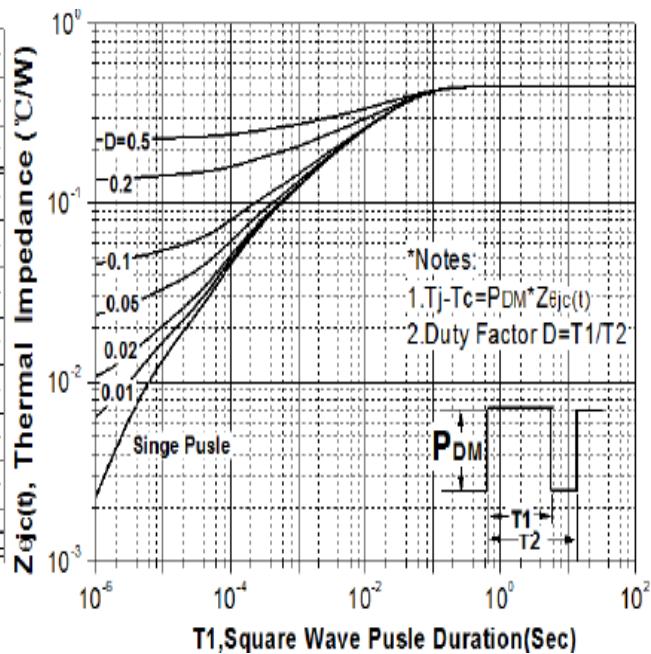
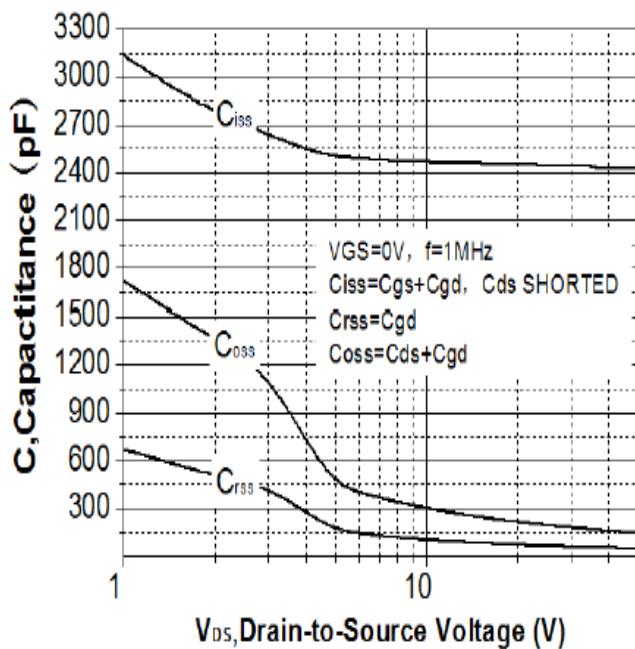
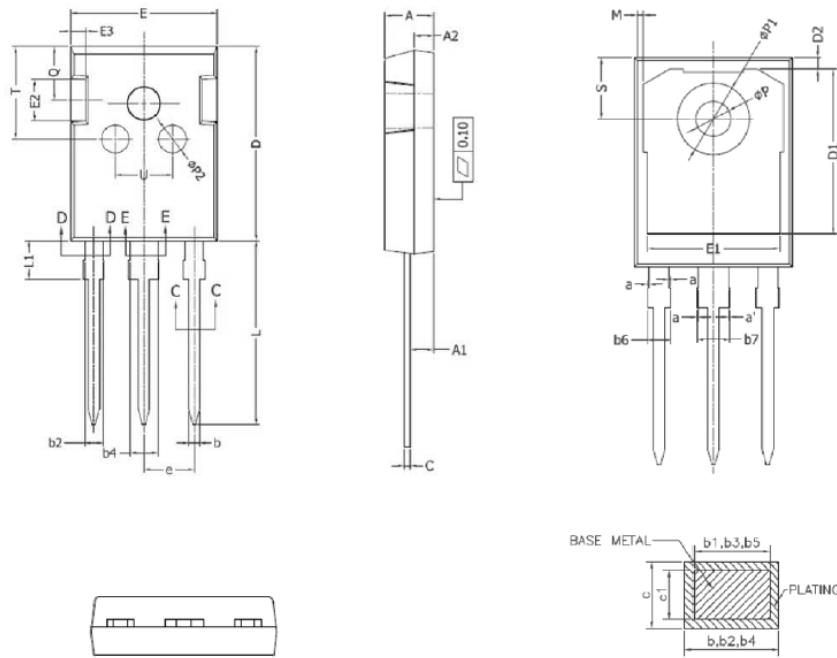


Fig. 8 Typical Switching Time vs. R_g at $T_c=25^\circ\text{C}$,
 $V_{CE}=400\text{V}$, $V_{GE}=15\text{V}$, $I_c=15\text{A}$ and $R_g=10.5\Omega$



Package Information

TO-247


 COMMON DIMENSIONS
 (UNITS OF MEASURE = MILLIMETER)

| SYMBOL | MIN | NOM | MAX |
|--------|-----------|-------|-------|
| A | 4.90 | 5.00 | 5.10 |
| A1 | 2.31 | 2.41 | 2.51 |
| A2 | 1.90 | 2.00 | 2.10 |
| a | 0 | — | 0.15 |
| a' | 0 | — | 0.15 |
| b | 1.16 | — | 1.26 |
| b1 | 1.15 | 1.2 | 1.22 |
| b2 | 1.96 | — | 2.06 |
| b3 | 1.95 | 2.00 | 2.02 |
| b4 | 2.96 | — | 3.06 |
| b5 | 2.96 | 3.00 | 3.02 |
| b6 | --- | — | 2.25 |
| b7 | --- | — | 3.25 |
| c | 0.59 | — | 0.66 |
| c1 | 0.58 | 0.60 | 0.62 |
| D | 20.90 | 21.00 | 21.10 |
| D1 | 16.25 | 16.55 | 16.85 |
| D2 | 1.05 | 1.17 | 1.35 |
| E | 15.70 | 15.80 | 15.90 |
| E1 | 13.10 | 13.30 | 13.50 |
| E2 | 4.40 | 4.50 | 4.60 |
| E3 | 1.50 | 1.60 | 1.70 |
| e | 5.436 BSC | | |
| L | 19.80 | 19.92 | 20.10 |
| L1 | — | — | 4.30 |
| M | 0.35 | — | 0.95 |
| P | 3.40 | 3.50 | 3.60 |
| P1 | 7.00 | — | 7.40 |
| P2 | 2.40 | 2.50 | 2.60 |
| Q | 5.60 | — | 6.00 |
| S | 6.05 | 6.15 | 6.25 |
| T | 9.80 | — | 10.20 |
| U | 6.00 | — | 6.40 |

NOTES:

 ALL DIMENSIONS REFER TO JEDEC STANDARD TO-247 AND
 DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.

 EJECTION MARK DEPTH $0.10^{+0.15}_{-0.10}$